

LT1963A Series

1.5A, Low Noise, Fast Transient Response LDO Regulators

FEATURES

- **Optimized for Fast Transient Response**
- **Output Current: 1.5A**
- **Dropout Voltage: 340mV**
- Low Noise: 40µV_{RMS} (10Hz to 100kHz)
- **1mA Quiescent Current**
- No Protection Diodes Needed
- Controlled Quiescent Current in Dropout
- Fixed Output Voltages: 1.5V, 1.8V, 2.5V, 3.3V
- Adjustable Output from 1.21V to 20V
- <1uA Quiescent Current in Shutdown
- Stable with 10µF Output Capacitor*
- Stable with Ceramic Capacitors*
- **Reverse Battery Protection**
- No Reverse Current
- Thermal Limiting
- 5-Lead TO-220, DD, 3-Lead SOT-223 and 8-Lead SO Packages

APPLICATIONS

3.3V to 2.5V Logic Power Supplies

TYPICAL APPLICATION

Post Regulator for Switching Supplies

DESCRIPTION

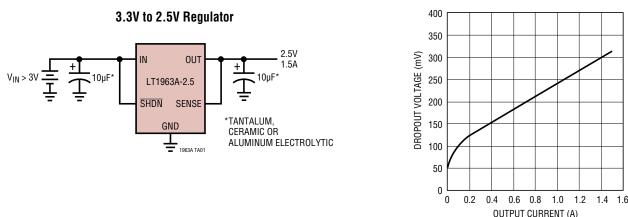
The LT®1963A series are low dropout regulators optimized for fast transient response. The devices are capable of supplying 1.5A of output current with a dropout voltage of 340mV. Operating quiescent current is 1mA, dropping to <1µA in shutdown. Quiescent current is well controlled; it does not rise in dropout as it does with many other regulators. In addition to fast transient response, the LT1963A regulators have very low output noise which makes them ideal for sensitive RF supply applications.

Output voltage range is from 1.21V to 20V. The LT1963A regulators are stable with output capacitors as low as 10µF. Internal protection circuitry includes reverse battery protection, current limiting, thermal limiting and reverse current protection. The devices are available in fixed output voltages of 1.5V, 1.8V, 2.5V, 3.3V and as an adjustable device with a 1.21V reference voltage. The LT1963A regulators are available in 5-lead TO-220, DD, 3-lead SOT-223, 8-lead SO and 16-lead TSSOP packages.

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Dropout Voltage

*See Applications Information Section.



1963A TA02



ABSOLUTE MAXIMUM RATINGS

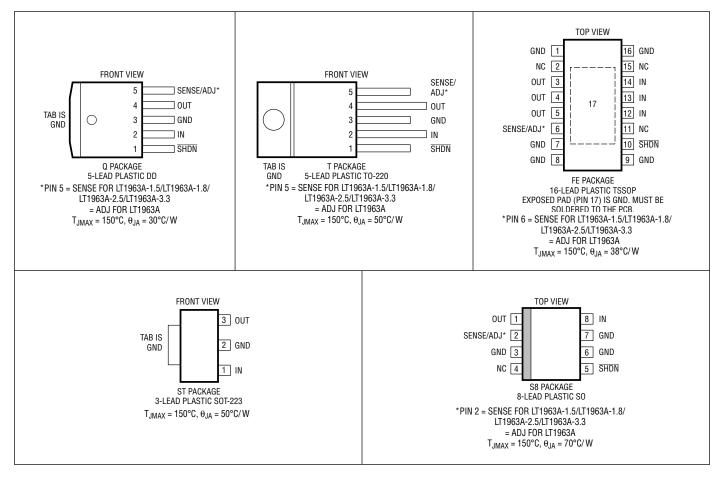
(Note 1)

IN Pin Voltage	± 20V
OUT Pin Voltage	±20V
Input to Output Differential Voltage (Note 2)	±20V
SENSE Pin Voltage	±20V
ADJ Pin Voltage	
SHDN Pin Voltage	±20V
Output Short-Circuit Duration	

Operating Junction Temperature Range (Note 3)

LT1963AE	40°C to 125°C
LT1963AI	40°C to 125°C
LT1963AMP	55°C to 125°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering,	10 sec) 300°C

PIN CONFIGURATION





ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT1963AEQ#PBF	LT1963AEQ#TRPBF	LT1963AEQ	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AIQ#PBF	LT1963AIQ#TRPBF	LT1963AIQ	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AMPQ#PBF	LT1963AMPQ#TRPBF	LT1963AMPQ	5-Lead Plastic DD-Pak	-55°C to 125°C
LT1963AEQ-1.5#PBF	LT1963AEQ-1.5#TRPBF	LT1963AEQ-1.5	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AEQ-1.8#PBF	LT1963AEQ-1.8#TRPBF	LT1963AEQ-1.8	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AEQ-2.5#PBF	LT1963AEQ-2.5#TRPBF	LT1963AEQ-2.5	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AEQ-3.3#PBF	LT1963AEQ-3.3#TRPBF	LT1963AEQ-3.3	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AET#PBF	LT1963AET#TRPBF	LT1963AET	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AIT#PBF	LT1963AIT#TRPBF	LT1963AIT	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-1.5#PBF	LT1963AET-1.5#TRPBF	LT1963AET-1.5	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-1.8#PBF	LT1963AET-1.8#TRPBF	LT1963AET-1.8	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-2.5#PBF	LT1963AET-2.5#TRPBF	LT1963AET-2.5	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-3.3#PBF	LT1963AET-3.3#TRPBF	LT1963AET-3.3	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AEFE#PBF	LT1963AEFE#TRPBF	1963AEFE	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AIFE#PBF	LT1963AIFE#TRPBF	1963AIFE	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-1.5#PBF	LT1963AEFE-1.5#TRPBF	1963AEFE15	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-1.8#PBF	LT1963AEFE-1.8#TRPBF	1963AEFE18	16-Lead Plastic TSSOP	-40°C to 125°C
_T1963AEFE-2.5#PBF	LT1963AEFE-2.5#TRPBF	1963AEFE25	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-3.3#PBF	LT1963AEFE-3.3#TRPBF	1963AEFE33	16-Lead Plastic TSSOP	-40°C to 125°C
_T1963AEST-1.5#PBF	LT1963AEST-1.5#TRPBF	963A15	3-Lead Plastic SOT-223	-40°C to 125°C
_T1963AEST-1.8#PBF	LT1963AEST-1.8#TRPBF	963A18	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AEST-2.5#PBF	LT1963AEST-2.5#TRPBF	963A25	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AEST-3.3#PBF	LT1963AEST-3.3#TRPBF	963A33	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AES8#PBF	LT1963AES8#TRPBF	1963A	8-Lead Plastic SO	-40°C to 125°C
LT1963AIS8#PBF	LT1963AIS8#TRPBF	1963A	8-Lead Plastic SO	-40°C to 125°C
LT1963AMPS8#PBF	LT1963AMPS8#TRPBF	963AMP	8-Lead Plastic SO	-55°C to 125°C
LT1963AES8-1.5#PBF	LT1963AES8-1.5#TRPBF	963A15	8-Lead Plastic SO	-40°C to 125°C
LT1963AES8-1.8#PBF	LT1963AES8-1.8#TRPBF	963A18	8-Lead Plastic SO	-40°C to 125°C
LT1963AES8-2.5#PBF	LT1963AES8-2.5#TRPBF	963A25	8-Lead Plastic SO	-40°C to 125°C
LT1963AES8-3.3#PBF	LT1963AES8-3.3#TRPBF	963A33	8-Lead Plastic SO	-40°C to 125°C
LEAD BASED FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT1963AEQ	LT1963AEQ#TR	LT1963AEQ	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AIQ	LT1963AIQ#TR	LT1963AIQ	5-Lead Plastic DD-Pak	-40°C to 125°C
_T1963AMPQ	LT1963AMPQ#TR	LT1963AMPQ	5-Lead Plastic DD-Pak	-55°C to 125°C
LT1963AEQ-1.5	LT1963AEQ-1.5#TR	LT1963AEQ-1.5	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AEQ-1.8	LT1963AEQ-1.8#TR	LT1963AEQ-1.8	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AEQ-2.5	LT1963AEQ-2.5#TR	LT1963AEQ-2.5	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AEQ-3.3	LT1963AEQ-3.3#TR	LT1963AEQ-3.3	5-Lead Plastic DD-Pak	-40°C to 125°C
LT1963AET	LT1963AET#TR	LT1963AET	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AIT	LT1963AIT#TR	LT1963AIT	5-Lead Plastic TO-220	-40°C to 125°C
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ORDER INFORMATION

LEAD BASED FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT1963AET-1.5	LT1963AET-1.5#TR	LT1963AET-1.5	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-1.8	LT1963AET-1.8#TR	LT1963AET-1.8	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-2.5	LT1963AET-2.5#TR	LT1963AET-2.5	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AET-3.3	LT1963AET-3.3#TR	LT1963AET-3.3	5-Lead Plastic TO-220	-40°C to 125°C
LT1963AEFE	LT1963AEFE#TR	1963AEFE	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AIFE	LT1963AIFE#TR	1963AIFE	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-1.5	LT1963AEFE-1.5#TR	1963AEFE15	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-1.8	LT1963AEFE-1.8#TR	1963AEFE18	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-2.5	LT1963AEFE-2.5#TR	1963AEFE25	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEFE-3.3	LT1963AEFE-3.3#TR	1963AEFE33	16-Lead Plastic TSSOP	-40°C to 125°C
LT1963AEST-1.5	LT1963AEST-1.5#TR	963A15	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AEST-1.8	LT1963AEST-1.8#TR	963A18	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AEST-2.5	LT1963AEST-2.5#TR	963A25	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AEST-3.3	LT1963AEST-3.3#TR	963A33	3-Lead Plastic SOT-223	-40°C to 125°C
LT1963AES8	LT1963AES8#TR	1963A	8-Lead Plastic SO	-40°C to 125°C
LT1963AIS8	LT1963AIS8#TR	1963A	8-Lead Plastic SO	-40°C to 125°C
LT1963AMPS8	LT1963AMPS8#TR	963AMP	8-Lead Plastic SO	-55°C to 125°C
LT1963AES8-1.5	LT1963AES8-1.5#TR	963A15	8-Lead Plastic SO	-40°C to 125°C
LT1963AES8-1.8	LT1963AES8-1.8#TR	963A18	8-Lead Plastic SO	-40°C to 125°C
LT1963AES8-2.5	LT1963AES8-2.5#TR	963A25	8-Lead Plastic SO	-40°C to 125°C
LT1963AES8-3.3	LT1963AES8-3.3#TR	963A33	8-Lead Plastic SO	-40°C to 125°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on lead free part marking, go to: http://www.linear.com/leadfree/ For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/



ELECTRICAL CHARACTERISTICS The \bullet denotes specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (Note 3)

PARAMETER	CONDITIONS	_	MIN	ТҮР	МАХ	UNITS
Minimum Input Voltage (Notes 4,12)	$I_{LOAD} = 0.5A$ $I_{LOAD} = 1.5A$	•		1.9 2.1	2.5	V V
Regulated Output Voltage (Note 5)	LT1963A-1.5 $V_{IN} = 2.21V, I_{LOAD} = 1mA$ 2.5V < $V_{IN} < 20V, 1mA < I_{LOAD} < 1.5A$	•	1.477 1.447	1.500 1.500	1.523 1.545	V V
	LT1963A-1.8 V _{IN} = 2.3V, I _{LOAD} = 1mA 2.8V < V _{IN} < 20V, 1mA < I _{LOAD} < 1.5A	•	1.773 1.737	1.800 1.800	1.827 1.854	V V
	LT1963A-2.5 $V_{IN} = 3V$, $I_{LOAD} = 1mA$ $3.5V < V_{IN} < 20V$, $1mA < I_{LOAD} < 1.5A$	•	2.462 2.412	2.500 2.500	2.538 2.575	V V
	LT1963A-3.3 V _{IN} = 3.8V, I _{LOAD} = 1mA 4.3V < V _{IN} < 20V, 1mA < I _{LOAD} < 1.5A	•	3.250 3.200	3.300 3.300	3.350 3.400	V V
ADJ Pin Voltage (Notes 4, 5)	LT1963A V _{IN} = 2.21V, I _{LOAD} = 1mA 2.5V < V _{IN} < 20V, 1mA < I _{LOAD} < 1.5A	•	1.192 1.174	1.210 1.210	1.228 1.246	V V
Line Regulation	$ \begin{array}{cccc} LT1963A-1.5 & \Delta V_{IN} = 2.21 V \ to \ 20V, \ I_{LOAD} = 1 mA \\ LT1963A-1.8 & \Delta V_{IN} = 2.3 V \ to \ 20V, \ I_{LOAD} = 1 mA \\ LT1963A-2.5 & \Delta V_{IN} = 3V \ to \ 20V, \ I_{LOAD} = 1 mA \\ LT1963A-3.3 & \Delta V_{IN} = 3.8V \ to \ 20V, \ I_{LOAD} = 1 mA \\ LT1963A \ (Note \ 4) & \Delta V_{IN} = 2.21 V \ to \ 20V, \ I_{LOAD} = 1 mA \end{array} $	• • • •		2.0 2.5 3.0 3.5 1.5	6 7 10 10 5	mV mV mV mV mV
Load Regulation	LT1963A-1.5 V_{IN} = 2.5V, ΔI_{LOAD} = 1mA to 1.5A V_{IN} = 2.5V, ΔI_{LOAD} = 1mA to 1.5A	•		2	9 18	mV mV
	LT1963A-1.8 V_{IN} = 2.8V, ΔI_{LOAD} = 1mA to 1.5A V_{IN} = 2.8V, ΔI_{LOAD} = 1mA to 1.5A	•		2	10 20	mV mV
	LT1963A-2.5 $V_{IN} = 3.5V, \Delta I_{LOAD} = 1 \text{ mA to } 1.5 V_{IN} = 3.5V, \Delta I_{LOAD} = 1 \text{ mA to } 1.5 A$	•		2.5	15 30	mV mV
	LT1963A-3.3 $V_{IN} = 4.3V, \Delta I_{LOAD} = 1 \text{ mA to } 1.5 \text{A}$ $V_{IN} = 4.3V, \Delta I_{LOAD} = 1 \text{ mA to } 1.5 \text{A}$	•		3	20 35	mV mV
	LT1963A (Note 4) V_{IN} = 2.5V, ΔI_{LOAD} = 1mA to 1.5A V_{IN} = 2.5V, ΔI_{LOAD} = 1mA to 1.5A	•		2	8 15	mV mV
Dropout Voltage VIN = V _{OUT(NOMINAL)}	I _{LOAD} = 1mA I _{LOAD} = 1mA	•		0.02	0.06 0.10	V V
(Notes 6, 7, 12)	$I_{LOAD} = 100mA$ $I_{LOAD} = 100mA$	•		0.10	0.17 0.22	V V
	$I_{LOAD} = 500$ mA $I_{LOAD} = 500$ mA	•		0.19	0.27 0.35	V V
	$I_{LOAD} = 1.5A$ $I_{LOAD} = 1.5A$	•		0.34	0.45 0.55	V V
GND Pin Current V _{IN} = V _{OUT(NOMINAL)} + 1V (Notes 6, 8)	$I_{LOAD} = 0mA$ $I_{LOAD} = 1mA$ $I_{LOAD} = 100mA$ $I_{LOAD} = 500mA$ $I_{LOAD} = 1.5A$	• • • •		1.0 1.1 3.8 15 80	1.5 1.6 5.5 25 120	mA mA mA mA
Output Voltage Noise	$C_{OUT} = 10\mu$ F, $I_{LOAD} = 1.5$ A, BW = 10Hz to 100kHz			40		μV _{RMS}
ADJ Pin Bias Current	(Notes 4, 9)			3	10	μA
Shutdown Threshold	V _{OUT} = Off to On V _{OUT} = On to Off	•	0.25	0.90 0.75	2	V V
SHDN Pin Current (Note 10)	V _{SHDN} = 0V V _{SHDN} = 20V			0.01 3	1 30	μA μA
Quiescent Current in Shutdown	$V_{IN} = 6V, V_{\overline{SHDN}} = 0V$			0.01	1	μA

ELECTRICAL CHARACTERISTICS The \bullet denotes specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (Note 3)

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Ripple Rejection	$V_{IN} - V_{OUT} = 1.5V (Avg), V_{RIPPLE} = 0.5V_{P-P}, f_{RIPPLE} = 120Hz, I_{LOAD} = 0.75A$	55	63		dB	
Current Limit	$V_{IN} = 7V, V_{OUT} = 0V$ $V_{IN} = V_{OUT(NOMINAL)} + 1V, \Delta V_{OUT} = -0.1V$	•	1.6	2		A A
Input Reverse Leakage Current (Note 13)	Q, T, S8 Packages $V_{IN} = -20V$, $V_{OUT} = 0$ ST Package $V_{IN} = -20V$, $V_{OUT} = 0$	•			1 2	mA mA
Reverse Output Current (Note 11)	$ \begin{array}{llllllllllllllllllllllllllllllllllll$			600 600 600 600 300	1200 1200 1200 1200 600	μΑ μΑ μΑ μΑ

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: Absolute maximum input to output differential voltage can not be achieved with all combinations of rated IN pin and OUT pin voltages. With the IN pin at 20V, the OUT pin may not be pulled below 0V. The total measured voltage from IN to OUT can not exceed \pm 20V.

Note 3: The LT1963A regulators are tested and specified under pulse load conditions such that $T_J \approx T_A$. The LT1963AE is 100% tested at $T_A = 25^{\circ}$ C. Performance at -40°C and 125°C is assured by design, characterization and correlation with statistical process controls. The LT1963AI is guaranteed over the full -40°C to 125°C operating junction temperature range. The LT1963AMP is 100% tested and guaranteed over the -55°C to 125°C operating junction temperature range.

Note 4: The LT1963A (adjustable version) is tested and specified for these conditions with the ADJ pin connected to the OUT pin.

Note 5: Operating conditions are limited by maximum junction temperature. The regulated output voltage specification will not apply for all possible combinations of input voltage and output current. When operating at maximum input voltage, the output current range must be limited. When operating at maximum output current, the input voltage range must be limited.

Note 6: To satisfy requirements for minimum input voltage, the LT1963A (adjustable version) is tested and specified for these conditions with an external resistor divider (two 4.12k resistors) for an output voltage of 2.4V. The external resistor divider will add a 300µA DC load on the output.

Note 7: Dropout voltage is the minimum input to output voltage differential needed to maintain regulation at a specified output current. In dropout, the output voltage will be equal to: $V_{IN} - V_{DROPOUT}$.

Note 8: GND pin current is tested with $V_{IN} = V_{OUT(NOMINAL)} + 1V$ and a current source load. The GND pin current will decrease at higher input voltages.

Note 9: ADJ pin bias current flows into the ADJ pin.

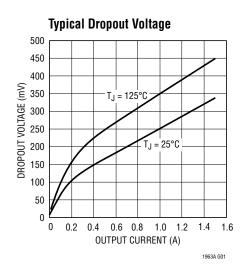
Note 10: SHDN pin current flows into the SHDN pin.

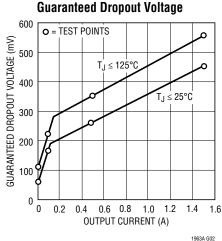
Note 11: Reverse output current is tested with the IN pin grounded and the OUT pin forced to the rated output voltage. This current flows into the OUT pin and out the GND pin.

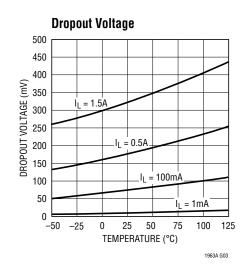
Note 12: For the LT1963A, LT1963A-1.5 and LT1963A-1.8 dropout voltage will be limited by the minimum input voltage specification under some output voltage/load conditions.

Note 13: For the ST package, the input reverse leakage current increases due to the additional reverse leakage current for the SHDN pin, which is tied internally to the IN pin.



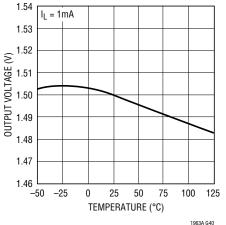




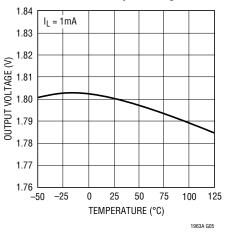


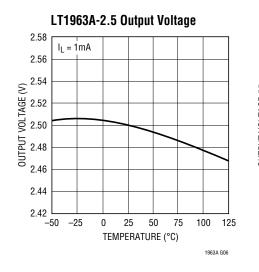
Quiescent Current 1.4 1.2 1963A-1.5/1.8/-2.5/-3.3 QUIESCENT CURRENT (mA) 1.0 0.8 LT1963A 0.6 0.4 $V_{IN} = 6V$ 0.2 = 0 R_L = ∞, I_L $V_{SHDN} = V_{IN}$ 0 -50 -25 0 25 50 75 100 125 TEMPERATURE (°C) 1963A G04

LT1963A-1.5 Output Voltage

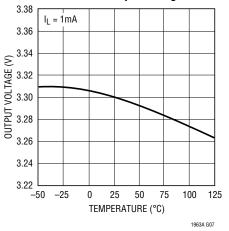


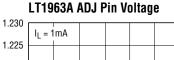
LT1963A-1.8 Output Voltage

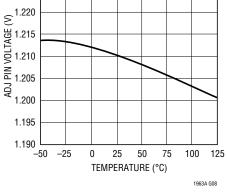




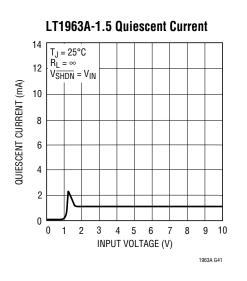
LT1963A-3.3 Output Voltage

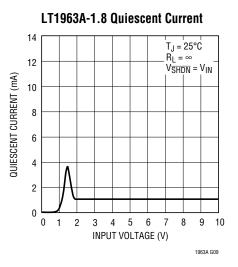




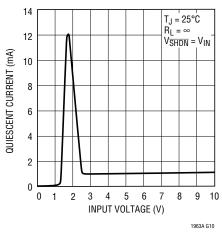




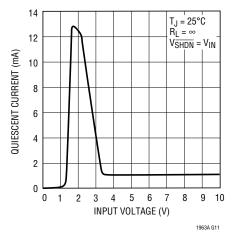




LT1963A-2.5 Quiescent Current

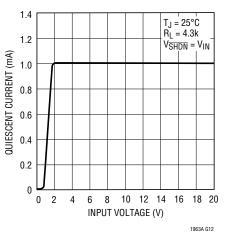


LT1963A-3.3 Quiescent Current

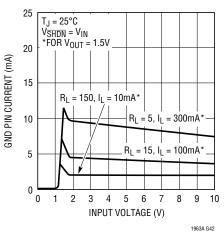


LT1963A-1.8 GND Pin Current 25 T_{.1} = 25°C $V_{SHDN} = V_{IN}$ *FOR V_{OUT} = 1.8V 20 **GND PIN CURRENT (mA)** 15 10 R_L = 6, I_L = 300mA 5 18, I_L = 100mA R = 180, I_L = 10mA* R 0 0 1 2 3 4 5 6 7 8 9 10 INPUT VOLTAGE (V) 19634 G13

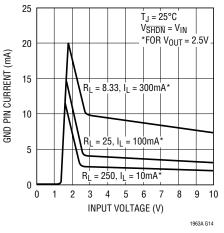
LT1963A Quiescent Current



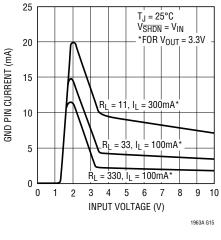
LT1963A-1.5 GND Pin Current



LT1963A-2.5 GND Pin Current

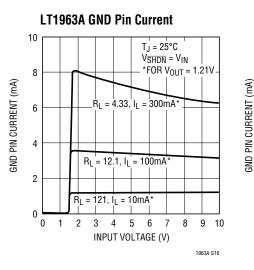


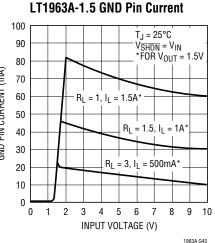
LT1963A-3.3 GND Pin Current



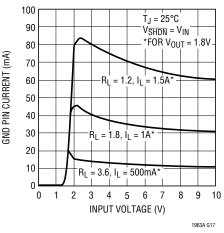
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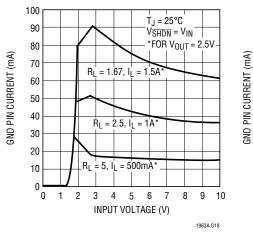




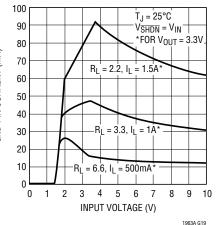
LT1963A-1.8 GND Pin Current



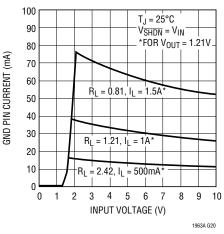
LT1963A-2.5 GND Pin Current



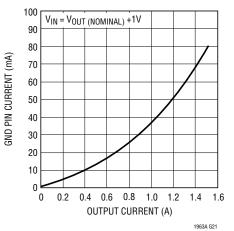
LT1963A-3.3 GND Pin Current



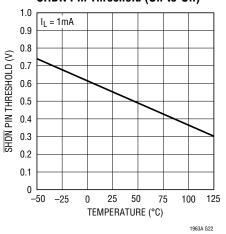
LT1963A GND Pin Current



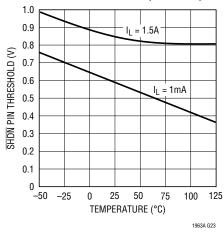
GND Pin Current vs ILOAD



SHDN Pin Threshold (On-to-Off)



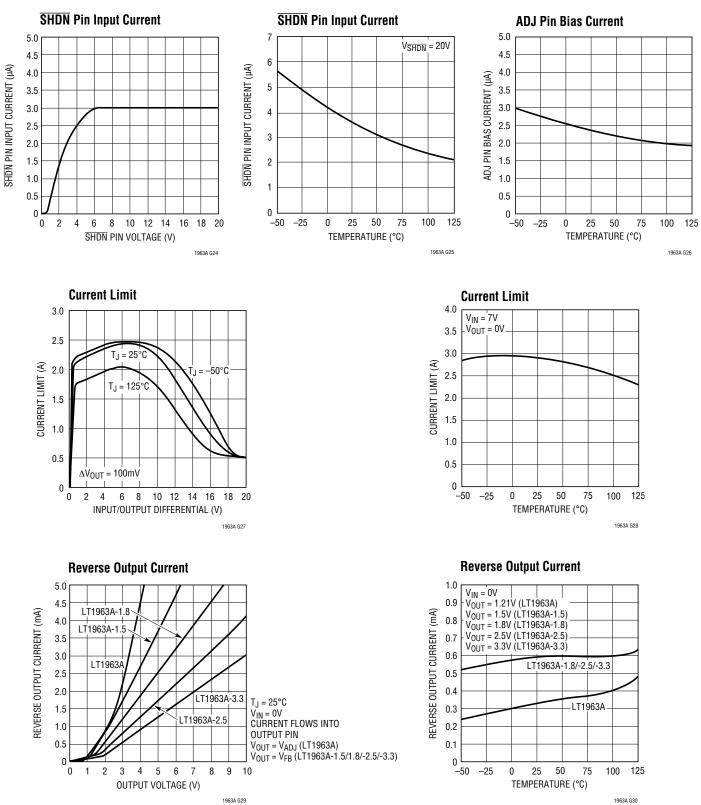
SHDN Pin Threshold (Off-to-On)





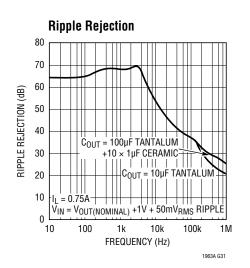


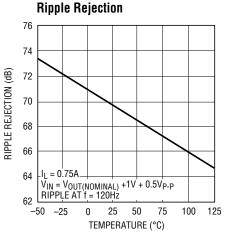
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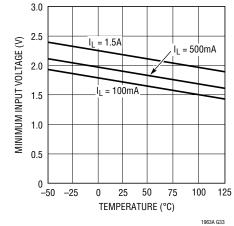
1963A G30

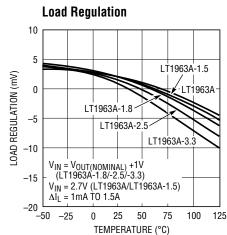






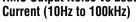
LT1963A Minimum Input Voltage

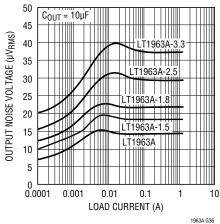




RMS Output Noise vs Load

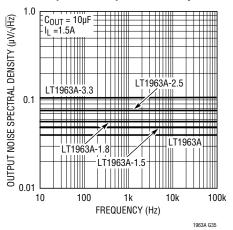
1963A G34



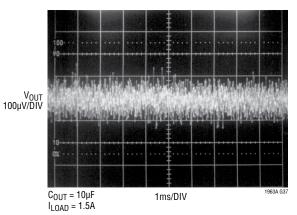


Output Noise Spectral Density

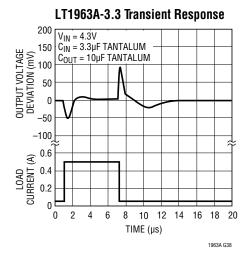
1963A G32

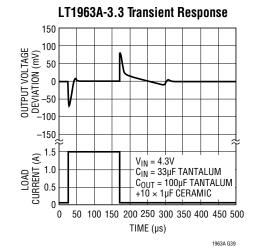


LT1963A-3.3 10Hz to 100kHz Output Noise



LINEAR TECHNOLOGY





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PIN FUNCTIONS

OUT: Output. The output supplies power to the load. A minimum output capacitor of 10μ F is required to prevent oscillations. Larger output capacitors will be required for applications with large transient loads to limit peak voltage transients. See the Applications Information section for more information on output capacitance and reverse output characteristics.

SENSE: Sense. For fixed voltage versions of the LT1963A (LT1963A-1.5/LT1963A-1.8/LT1963A-2.5/LT1963A-3.3), the SENSE pin is the input to the error amplifier. Optimum regulation will be obtained at the point where the SENSE pin is connected to the OUT pin of the regulator. In critical applications, small voltage drops are caused by the resistance (R_P) of PC traces between the regulator and the load. These may be eliminated by connecting the SENSE pin to the output at the load as shown in Figure 1 (Kelvin Sense Connection). Note that the voltage drop across the external PC traces will add to the dropout voltage of the regulator. The SENSE pin bias current is 600µA at the nominal rated output voltage. The SENSE pin can be pulled below ground (as in a dual supply system where the regulator load is returned to a negative supply) and still allow the device to start and operate.

ADJ: Adjust. For the adjustable LT1963A, this is the input to the error amplifier. This pin is internally clamped to \pm 7V. It has a bias current of 3µA which flows into the pin. The ADJ pin voltage is 1.21V referenced to ground and the output voltage range is 1.21V to 20V.

SHDN: Shutdown. The SHDN pin is used to put the LT1963A regulators into a low power shutdown state. The output will

be off when the SHDN pin is pulled low. The SHDN pin can be driven either by 5V logic or open-collector logic with a pull-up resistor. The pull-up resistor is required to supply the pull-up current of the open-collector gate, normally several microamperes, and the SHDN pin current, typically 3μ A. If unused, the SHDN pin must be connected to V_{IN}. The device will be in the low power shutdown state if the SHDN pin is not connected.

IN: Input. Power is supplied to the device through the IN pin. A bypass capacitor is required on this pin if the device is more than six inches away from the main input filter capacitor. In general, the output impedance of a battery rises with frequency, so it is advisable to include a bypass capacitor in battery-powered circuits. A bypass capacitor in the range of 1μ F to 10μ F is sufficient. The LT1963A regulators are designed to withstand reverse voltages on the IN pin with respect to ground and the OUT pin. In the case of a reverse input, which can happen if a battery is plugged in backwards, the device will act as if there is a diode in series with its input. There will be no reverse current flow into the regulator and no reverse voltage will appear at the load. The device will protect both itself and the load.

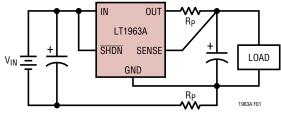


Figure 1. Kelvin Sense Connection



The LT1963A series are 1.5A low dropout regulators optimized for fast transient response. The devices are capable of supplying 1.5A at a dropout voltage of 350mV. The low operating quiescent current (1mA) drops to less than 1µA in shutdown. In addition to the low quiescent current, the LT1963A regulators incorporate several protection features which make them ideal for use in battery-powered systems. The devices are protected against both reverse input and reverse output voltages. In battery backup applications where the output can be held up by a backup battery when the input is pulled to ground, the LT1963A-X acts like it has a diode in series with its output and prevents reverse current flow. Additionally, in dual supply applications where the regulator load is returned to a negative supply, the output can be pulled below ground by as much as 20V and still allow the device to start and operate.

Adjustable Operation

The adjustable version of the LT1963A has an output voltage range of 1.21V to 20V. The output voltage is set by the ratio of two external resistors as shown in Figure 2. The device servos the output to maintain the voltage at the ADJ pin at 1.21V referenced to ground. The current in R1 is then equal to 1.21V/R1 and the current in R2 is the current in R1 plus the ADJ pin bias current. The ADJ pin bias current, 3μ A at 25°C, flows through R2 into the ADJ pin. The output voltage can be calculated using the formula in Figure 2. The value of R1 should be less than 4.17k to minimize errors in the output voltage caused by the ADJ pin bias current. Note that in shutdown the output is turned off and the divider current will be zero.

The adjustable device is tested and specified with the ADJ pin tied to the OUT pin for an output voltage of 1.21V. Specifications for output voltages greater than 1.21V will be proportional to the ratio of the desired output voltage to 1.21V: $V_{OUT}/1.21V$. For example, load regulation for an output current change of 1mA to 1.5A is – 3mV typical at $V_{OUT} = 1.21V$. At $V_{OUT} = 5V$, load regulation is:

(5V/1.21V)(-3mV) = -12.4mV

Output Capacitors and Stability

The LT1963A regulator is a feedback circuit. Like any feedback circuit, frequency compensation is needed to

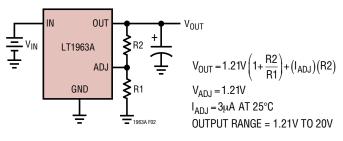


Figure 2. Adjustable Operation

make it stable. For the LT1963A, the frequency compensation is both internal and external—the output capacitor. The size of the output capacitor, the type of the output capacitor, and the ESR of the particular output capacitor all affect the stability.

In addition to stability, the output capacitor also affects the high frequency transient response. The regulator loop has a finite band width. For high frequency transient loads, recovery from a transient is a combination of the output capacitor and the bandwidth of the regulator. The LT1963A was designed to be easy to use and accept a wide variety of output capacitors. However, the frequency compensation is affected by the output capacitor and optimum frequency stability may require some ESR, especially with ceramic capacitors.

For ease of use, low ESR polytantalum capacitors (POSCAP) are a good choice for both the transient response and stability of the regulator. These capacitors have intrinsic ESR that improves the stability. Ceramic capacitors have extremely low ESR, and while they are a good choice in many cases, placing a small series resistance element will sometimes achieve optimum stability and minimize ringing. In all cases, a minimum of 10μ F is required while the maximum ESR allowable is 3Ω .

The place where ESR is most helpful with ceramics is low output voltage. At low output voltages, below 2.5V, some ESR helps the stability when ceramic output capacitors are used. Also, some ESR allows a smaller capacitor value to be used. When small signal ringing occurs with ceramics due to insufficient ESR, adding ESR or increasing the capacitor value improves the stability and reduces the ringing. Table 1 gives some recommended values of ESR to minimize ringing caused by fast, hard current transitions.





10µF	22µF	47µF	100µF			
20mΩ	$15 m\Omega$	10mΩ	$5 m \Omega$			
20mΩ	$15m\Omega$	10mΩ	$5 \text{m}\Omega$			
15mΩ	10mΩ	10mΩ	$5 \text{m}\Omega$			
5mΩ	$5 m\Omega$	$5 m\Omega$	$5 m\Omega$			
OmΩ	OmΩ	OmΩ	$5 \text{m}\Omega$			
0mΩ	OmΩ	OmΩ	OmΩ			
	20mΩ 20mΩ 15mΩ 5mΩ 0mΩ	20mΩ 15mΩ 20mΩ 15mΩ 15mΩ 10mΩ 5mΩ 5mΩ 0mΩ 0mΩ	20mΩ 15mΩ 10mΩ 20mΩ 15mΩ 10mΩ 15mΩ 10mΩ 10mΩ 5mΩ 5mΩ 5mΩ 0mΩ 0mΩ 0mΩ			

Table 1. Capacitor Minimum ESR

Figures 3 through 8 show the effect of ESR on the transient response of the regulator. These scope photos show the transient response for the LT1963A at three different output voltages with various capacitors and various values of ESR. The output load conditions are the same for all traces. In all cases there is a DC load of 500mA. The load steps up to 1A at the first transition and steps back to 500mA at the second transition.

At the worst case point of $1.2V_{OUT}$ with 10μ F C_{OUT} (Figure 3), a minimum amount of ESR is required. While $20m\Omega$ is enough to eliminate most of the ringing, a value closer to $50m\Omega$ provides a more optimum response. At 2.5V output with 10μ F C_{OUT} (Figure 4) the output rings at the transitions with 0Ω ESR but still settles to within 10mV in 20µs after the 0.5A load step. Once again a small value of ESR will provide a more optimum response.

At 5V_{OUT} with 10µF C_{OUT} (Figure 5) the response is well damped with 0 Ω ESR.

With a C_{OUT} of 100μ F at 0Ω ESR and an output of 1.2V (Figure 6), the output rings although the amplitude is only $20mV_{p-p}$. With C_{OUT} of 100μ F it takes only $5m\Omega$ to $20m\Omega$ of ESR to provide good damping at 1.2V output. Performance at 2.5V and 5V output with 100μ F C_{OUT} shows similar characteristics to the 10μ F case (see Figures 7-8). At $2.5V_{OUT}$ $5m\Omega$ to $20m\Omega$ can improve transient response. At $5V_{OUT}$ the response is well damped with 0Ω ESR.

Capacitor types with inherently higher ESR can be combined with $0m\Omega$ ESR ceramic capacitors to achieve both good high frequency bypassing and fast settling time. Figure 9 illustrates the improvement in transient response that can be seen when a parallel combination of ceramic and POSCAP capacitors are used. The output voltage is at the worst case value of 1.2V. Trace A, is with a 10 μ F ceramic output capacitor and shows significant ringing with a peak amplitude of 25mV. For Trace B, a 22 μ F/45m Ω POSCAP is added in parallel with the 10 μ F ceramic. The output is well damped and settles to within 10mV in less than 20 μ s.

For Trace C, a 100μ F/35m Ω POSCAP is connected in parallel with the 10μ F ceramic capacitor. In this case the peak output deviation is less than 20mV and the output settles in about 10 μ s. For improved transient response the value of the bulk capacitor (tantalum or aluminum electrolytic) should be greater than twice the value of the ceramic capacitor.

Tantalum and Polytantalum Capacitors

There is a variety of tantalum capacitor types available, with a wide range of ESR specifications. Older types have ESR specifications in the hundreds of $m\Omega$ to several Ohms. Some newer types of polytantalum with multi-electrodes have maximum ESR specifications as low as $5m\Omega$. In general the lower the ESR specification, the larger the size and the higher the price. Polytantalum capacitors have better surge capability than older types and generally lower ESR. Some types such as the Sanyo TPE and TPB series have ESR specifications in the $20m\Omega$ to $50m\Omega$ range, which provide near optimum transient response.

Aluminum Electrolytic Capacitors

Aluminum electrolytic capacitors can also be used with the LT1963A. These capacitors can also be used in conjunction with ceramic capacitors. These tend to be the cheapest and lowest performance type of capacitors. Care must be used in selecting these capacitors as some types can have ESR which can easily exceed the 3Ω maximum value.

Ceramic Capacitors

Extra consideration must be given to the use of ceramic capacitors. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. The most common dielectrics used are Z5U, Y5V, X5R and X7R. The Z5U and

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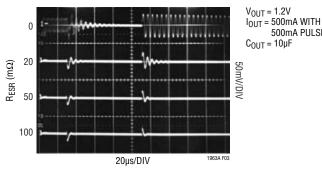


Figure 3

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20µs/DIV

Figure 4

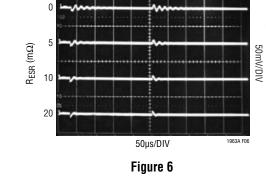
0

20

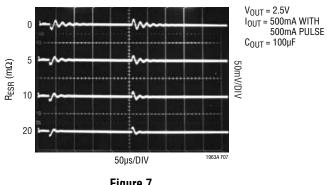
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100

R_{ESR} (mΩ)



 $V_{OUT} = 1.2V$ $I_{OUT} = 500$ mA WITH 500mA PULSE $C_{OUT} = 100 \mu F$





 $V_{OUT} = 5V$ $I_{OUT} = 500$ mA WITH 500mA PULSE $C_{OUT} = 100 \mu F$

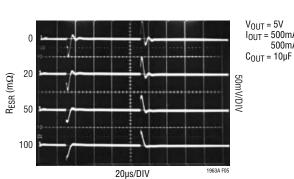


Figure 5



 $V_{OUT} = 2.5V$ $I_{OUT} = 500$ mA WITH 500mA PULSE

 $C_{OUT} = 10 \mu F$

50mV/DIV

1963A F04

А

В

С

R_{ESR} (mΩ)

500mA PULSE

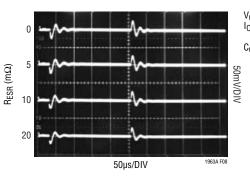


Figure 8

 $V_{OUT} = 1.2V$ $I_{OUT} = 500$ WITH 500 MA PULSE $C_{OUT} = 200$ $\begin{array}{l} \text{A}=10 \mu\text{F}\ \text{CERAMIC} \\ \text{B}=10 \mu\text{F}\ \text{CERAMIC}\ \text{II}\ 22 \mu\text{F}/45 m\Omega\ \text{POLY} \\ \text{C}=10 \mu\text{F}\ \text{CERAMIC}\ \text{II}\ 100 \mu\text{F}/35 m\Omega\ \text{POLY} \\ \end{array}$ 50mV/DIV

1963A F09



50µs/DIV

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Y5V dielectrics are good for providing high capacitances in a small package, but exhibit strong voltage and temperature coefficients as shown in Figures 10 and 11. When used with a 5V regulator, a 10 μ F Y5V capacitor can exhibit an effective value as low as 1 μ F to 2 μ F over the operating temperature range. The X5R and X7R dielectrics result in more stable characteristics and are more suitable for use as the output capacitor. The X7R type has better stability across temperature, while the X5R is less expensive and is available in higher values.

Voltage and temperature coefficients are not the only sources of problems. Some ceramic capacitors have a piezoelectric response. A piezoelectric device generates voltage across its terminals due to mechanical stress, similar to the way a piezoelectric accelerometer or microphone works. For a ceramic capacitor the stress can be induced by vibrations in the system or thermal transients.

"FREE" Resistance with PC Traces

The resistance values shown in Table 2 can easily be made using a small section of PC trace in series with the output capacitor. The wide range of non-critical ESR makes it easy to use PC trace. The trace width should be sized to handle the RMS ripple current associated with the load. The output capacitor only sources or sinks current for a few microseconds during fast output current transitions. There is no DC current in the output capacitor. Worst case ripple current will occur if the output load is a high frequency (>100kHz) square wave with a high peak value and fast edges (< 1 μ s). Measured RMS value for this case is 0.5 times the peak-to-peak current change. Slower edges or lower frequency will significantly reduce the RMS ripple current in the capacitor.

Table	2.	PC	T	race	Resistors	

		10m Ω	20m Ω	30m Ω
0.5oz C _U	Width	0.011 ["] (0.28mm)	0.011 ["] (0.28mm)	0.011 ["] (0.28mm)
	Length	0.102 ["] (2.6mm)	0.204 ["] (5.2mm)	0.307 ["] (7.8mm)
1.0oz C _U	Width	0.006 [°] (0.15mm)	0.006 [°] (0.15mm)	0.006 [°] (0.15mm)
	Length	0.110 [°] (2.8mm)	0.220 [°] (5.6mm)	0.330 [°] (8.4mm)
2.0oz C _U	Width	0.006 [°] (0.15mm)	0.006 [°] (0.15mm)	0.006 [°] (0.15mm)
	Length	0.224 [°] (5.7mm)	0.450 [°] (11.4mm)	0.670 [°] (17mm)

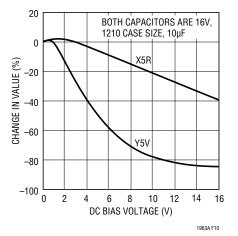


Figure 10. Ceramic Capacitor DC Bias Characteristics

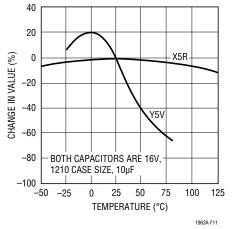


Figure 11. Ceramic Capacitor Temperature Characteristics

This resistor should be made using one of the inner layers of the PC board which are well defined. The resistivity is determined primarily by the sheet resistance of the copper laminate with no additional plating steps. Table 2 gives some sizes for 0.75A RMS current for various copper thicknesses. More detailed information regarding resistors made from PC traces can be found in Application Note 69, Appendix A.

Overload Recovery

Like many IC power regulators, the LT1963A-X has safe operating area protection. The safe area protection decreases the current limit as input-to-output voltage increases and keeps the power transistor inside a safe operating region for all values of input-to-output voltage. The protection is designed to provide some output current at all values of input-to-output voltage up to the device breakdown.

When power is first turned on, as the input voltage rises, the output follows the input, allowing the regulator to start up into very heavy loads. During the start-up, as the input voltage is rising, the input-to-output voltage differential is small, allowing the regulator to supply large output currents. With a high input voltage, a problem can occur wherein removal of an output short will not allow the output voltage to recover. Other regulators, such as the LT1085, also exhibit this phenomenon, so it is not unique to the LT1963A-X.

The problem occurs with a heavy output load when the input voltage is high and the output voltage is low. Common situations are immediately after the removal of a short-circuit or when the shutdown pin is pulled high after the input voltage has already been turned on. The load line for such a load may intersect the output current curve at two points. If this happens, there are two stable output operating points for the regulator. With this double intersection, the input power supply may need to be cycled down to zero and brought up again to make the output recover.

Output Voltage Noise

The LT1963A regulators have been designed to provide low output voltage noise over the 10Hz to 100kHz bandwidth while operating at full load. Output voltage noise is typically 40nV/ $\sqrt{\text{Hz}}$ over this frequency bandwidth for the LT1963A (adjustable version). For higher output voltages (generated by using a resistor divider), the output voltage noise will be gained up accordingly. This results in RMS noise over the 10Hz to 100kHz bandwidth of 14µV_{RMS} for the LT1963A increasing to 38µV_{RMS} for the LT1963A-3.3.

Higher values of output voltage noise may be measured when care is not exercised with regard to circuit layout and testing. Crosstalk from nearby traces can induce unwanted noise onto the output of the LT1963A-X. Power supply ripple rejection must also be considered; the LT1963A regulators do not have unlimited power supply rejection and will pass a small portion of the input noise through to the output.

Thermal Considerations

The power handling capability of the device is limited by the maximum rated junction temperature (125°C). The power dissipated by the device is made up of two components:

- 1. Output current multiplied by the input/output voltage differential: $(I_{OUT})(V_{IN} V_{OUT})$, and
- 2. GND pin current multiplied by the input voltage: (I_{GND}) (V_{IN}) .

The GND pin current can be found using the GND Pin Current curves in the Typical Performance Characteristics. Power dissipation will be equal to the sum of the two components listed above.

The LT1963A series regulators have internal thermal limiting designed to protect the device during overload conditions. For continuous normal conditions, the maximum junction temperature rating of 125°C must not be exceeded. It is important to give careful consideration to all sources of thermal resistance from junction to ambient. Additional heat sources mounted nearby must also be considered.

For surface mount devices, heat sinking is accomplished by using the heat spreading capabilities of the PC board and its copper traces. Copper board stiffeners and plated through-holes can also be used to spread the heat generated by power devices.



The following tables list thermal resistance for several different board sizes and copper areas. All measurements were taken in still air on 1/16" FR-4 board with one ounce copper.

COPPER AREA TOPSIDE* BACKSIDE			THERMAL RESISTANCE
		BOARD AREA	(JUNCTION-TO-AMBIENT)
2500mm ²	2500mm ²	2500mm ²	23°C/W
1000mm ²	2500mm ²	2500mm ²	25°C/W
125mm ²	2500mm ²	2500mm ²	33°C/W

Table 3. Q Package, 5-Lead DD

*Device is mounted on topside

Table 4. SO-8 Package, 8-Lead SO

COPPE	COPPER AREA		THERMAL RESISTANCE
TOPSIDE*	OPSIDE* BACKSIDE		(JUNCTION-TO-AMBIENT)
2500mm ²	2500mm ²	2500mm ²	55°C/W
1000mm ²	2500mm ²	2500mm ²	55°C/W
225mm ²	2500mm ²	2500mm ²	63°C/W
125mm ²	2500mm ²	2500mm ²	69°C/W

*Device is mounted on topside

Table 5. SOT-223 Package, 3-Lead SOT-223

COPPER AREA			THERMAL RESISTANCE
TOPSIDE*	BACKSIDE	BOARD AREA	(JUNCTION-TO-AMBIENT)
2500mm ²	2500mm ²	2500mm ²	42°C/W
1000mm ²	2500mm ²	2500mm ²	42°C/W
225mm ²	2500mm ²	2500mm ²	50°C/W
100mm ²	2500mm ²	2500mm ²	56°C/W
1000mm ²	1000mm ²	1000mm ²	49°C/W
1000mm ²	0mm ²	1000mm ²	52°C/W

*Device is mounted on topside

T Package, 5-Lead TO-220

Thermal Resistance (Junction-to-Case) = 4°C/W

Calculating Junction Temperature

Example: Given an output voltage of 3.3V, an input voltage range of 4V to 6V, an output current range of 0mA to 500mA and a maximum ambient temperature of 50°C, what will the maximum junction temperature be? The power dissipated by the device will be equal to:

 $I_{OUT(MAX)}(V_{IN(MAX)} - V_{OUT}) + I_{GND}(V_{IN(MAX)})$

where,

$$\begin{split} &I_{OUT(MAX)}=500\text{mA}\\ &V_{IN(MAX)}=6\text{V}\\ &I_{GND} \text{ at }(I_{OUT}=500\text{mA}, \text{ V}_{IN}=6\text{V})=10\text{mA}\\ &\text{So,} \end{split}$$

Using a DD package, the thermal resistance will be in the range of 23°C/W to 33°C/W depending on the copper area. So the junction temperature rise above ambient will be approximately equal to:

1.41W(28°C/W) = 39.5°C

The maximum junction temperature will then be equal to the maximum junction temperature rise above ambient plus the maximum ambient temperature or:

 $T_{JMAX} = 50^{\circ}C + 39.5^{\circ}C = 89.5^{\circ}C$

Protection Features

The LT1963A regulators incorporate several protection features which make them ideal for use in battery-powered circuits. In addition to the normal protection features associated with monolithic regulators, such as current limiting and thermal limiting, the devices are protected against reverse input voltages, reverse output voltages and reverse voltages from output to input.

Current limit protection and thermal overload protection are intended to protect the device against current overload conditions at the output of the device. For normal operation, the junction temperature should not exceed 125°C.

The input of the device will withstand reverse voltages of 20V. Current flow into the device will be limited to less than 1mA (typically less than 100 μ A) and no negative voltage will appear at the output. The device will protect both itself and the load. This provides protection against batteries that can be plugged in backward.



The output of the LT1963A can be pulled below ground without damaging the device. If the input is left open circuit or grounded, the output can be pulled below ground by 20V. For fixed voltage versions, the output will act like a large resistor, typically 5k or higher, limiting current flow to typically less than 600μ A. For adjustable versions, the output will act like an open circuit; no current will flow out of the pin. If the input is powered by a voltage source, the output will source the short-circuit current of the device and will protect itself by thermal limiting. In this case, grounding the SHDN pin will turn off the device and stop the output from sourcing the short-circuit current.

The ADJ pin of the adjustable device can be pulled above or below ground by as much as 7V without damaging the device. If the input is left open circuit or grounded, the ADJ pin will act like an open circuit when pulled below ground and like a large resistor (typically 5k) in series with a diode when pulled above ground.

In situations where the ADJ pin is connected to a resistor divider that would pull the ADJ pin above its 7V clamp voltage if the output is pulled high, the ADJ pin input current must be limited to less than 5mA. For example, a resistor divider is used to provide a regulated 1.5V output from the 1.21V reference when the output is forced to 20V. The top resistor of the resistor divider must be chosen to limit the current into the ADJ pin to less than 5mA when the ADJ pin is at 7V. The 13V difference between OUT and ADJ pins divided by the 5mA maximum current into the ADJ pin yields a minimum top resistor value of 2.6k. In circuits where a backup battery is required, several different input/output conditions can occur. The output voltage may be held up while the input is either pulled to ground, pulled to some intermediate voltage, or is left open circuit. Current flow back into the output will follow the curve shown in Figure 12.

When the IN pin of the LT1963A is forced below the OUT pin or the OUT pin is pulled above the IN pin, input current will typically drop to less than 2µA. This can happen if the input of the device is connected to a discharged (low voltage) battery and the output is held up by either a backup battery or a second regulator circuit. The state of the SHDN pin will have no effect on the reverse output current when the output is pulled above the input.

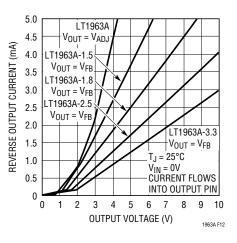
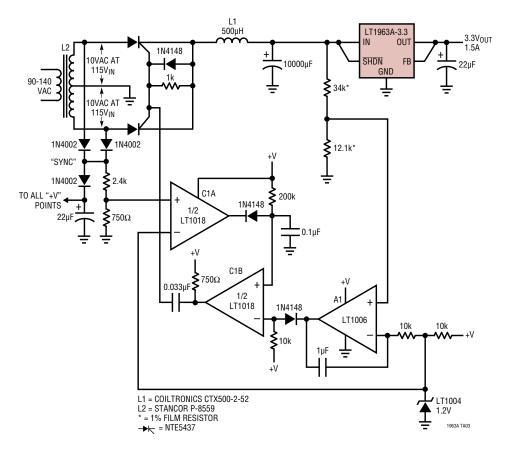


Figure 12. Reverse Output Current

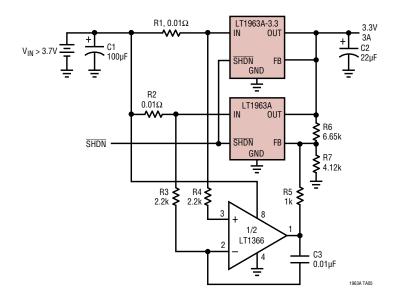


TYPICAL APPLICATIONS

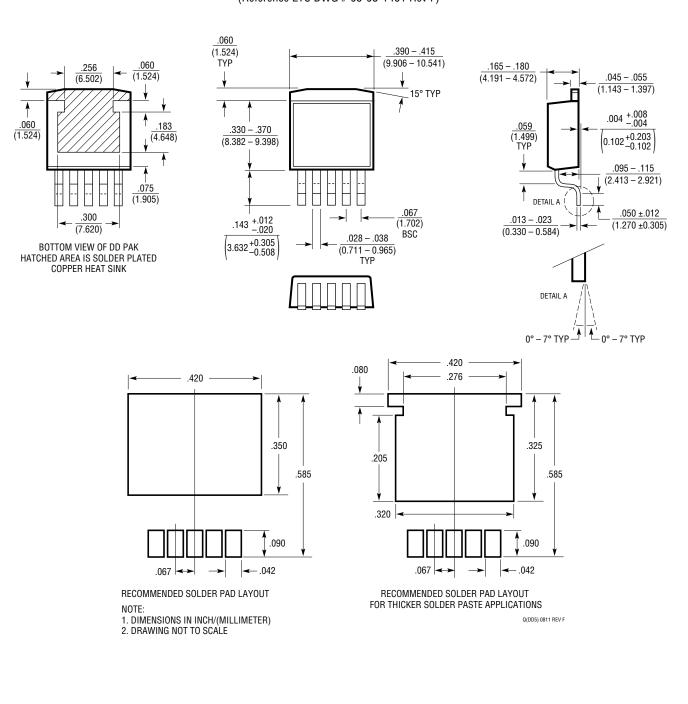


SCR Pre-Regulator Provides Efficiency Over Line Variations

Paralleling of Regulators for Higher Output Current



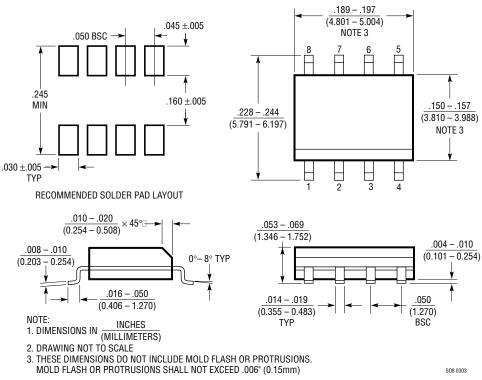






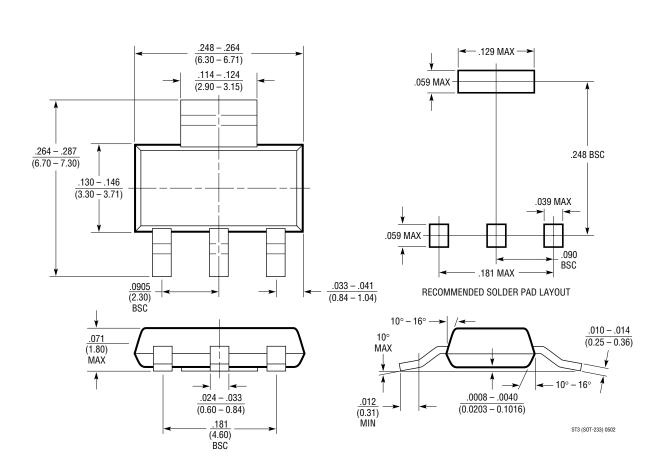


S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



S08 0303

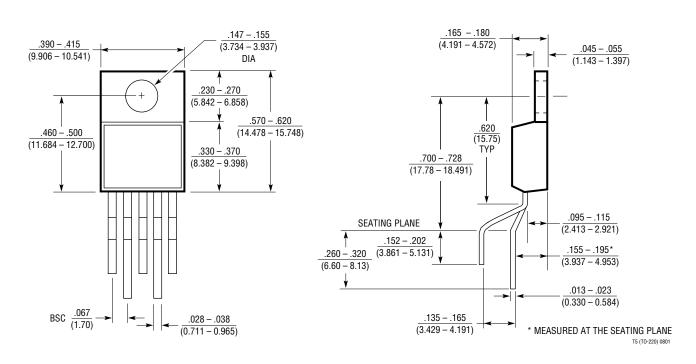




ST Package 3-Lead Plastic SOT-223 (Reference LTC DWG # 05-08-1630)



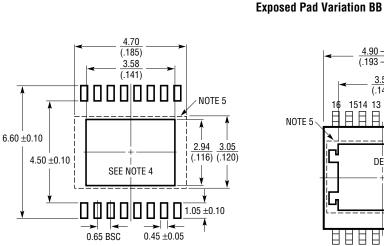




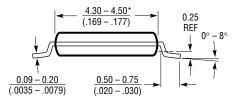
T Package 5-Lead Plastic TO-220 (Standard) (Reference LTC DWG # 05-08-1421)

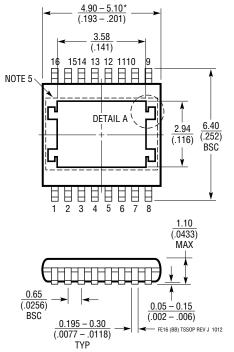


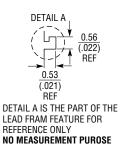




RECOMMENDED SOLDER PAD LAYOUT







NOTE:

- 1. CONTROLLING DIMENSION: MILLIMETERS
- 2. DIMENSIONS ARE IN MILLIMETERS (INCHES)
- 3. DRAWING NOT TO SCALE
- 4. RECOMMENDED MINIMUM PCB METAL SIZE
 - FOR EXPOSED PAD ATTACHMENT
- 5. BOTTOM EXPOSED PADDLE MAY HAVE METAL PROTRUSION IN THIS AREA. THIS REGION MUST BE FREE OF ANY EXPOSED TRACES OR VIAS ON PBC LAYOUT

FE Package 16-Lead Plastic TSSOP (4.4mm) (Reference LTC DWG # 05-08-1663 Rev J)

*DIMENSIONS DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.150mm (.006") PER SIDE

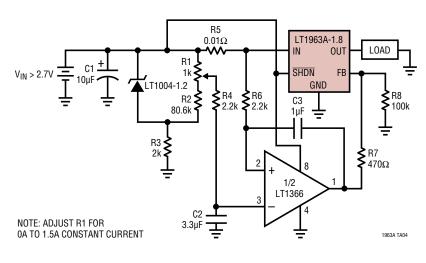


REVISION HISTORY (Revision history begins at Rev E)

REV	DATE	DESCRIPTION	
E	02/11	Updated FE and Q package drawings in Package Description section	
F	09/13	09/13 Replaced graphs with correct versions 16	



TYPICAL APPLICATION



Adjustable Current Source

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1175	500mA, Micropower, Negative LDO	V_{IN} : -20V to -4.3V, $V_{OUT(MIN)}$ = -3.8V, V_{DO} = 0.50V, I_Q = 45µA, I_{SD} 10µA, DD, SOT-223, PDIP8 Packages
LT1185	3A, Negative LDO	V_{IN} : -35V to -4.2V, $V_{OUT(MIN)}$ = -2.40V, V_{DO} = 0.80V, I_Q = 2.5mA, I_{SD} <1 $\mu A,$ TO220-5 Package
LT1761	100mA, Low Noise Micropower, LDO	V _{IN} : 1.8V to 20V, V _{OUT(MIN)} = 1.22V, V _{DO} = 0.30V, I _Q = 20µA, I _{SD} <1µA ThinSOT™ Package
LT1762	150mA, Low Noise Micropower, LDO	V_{IN} : 1.8V to 20V, $V_{OUT(MIN)}$ = 1.22V, V_{DO} = 0.30V, I_Q = 25µA, I_{SD} <1µA, MS8 Package
LT1763	500mA, Low Noise Micropower, LDO	V_{IN} : 1.8V to 20V, $V_{OUT(MIN)}$ = 1.22V, V_{DO} = 0.30V, I_Q = 30µA, I_{SD} <1µA, S8 Package
LT1764/ LT1764A	3A, Low Noise, Fast Transient Response, LDO	$V_{IN}:$ 2.7V to 20V, $V_{OUT(MIN)}$ = 1.21V, V_{DO} = 0.34V, I_Q = 1mA, I_{SD} <1µA, DD, TO220 Packages
LTC1844	150mA, Very Low Drop-Out LDO	$V_{IN}:$ 6.5V to 1.6V, $V_{OUT(MIN)}$ = 1.25V, V_{DO} = 0.08V, I_Q = 40µA, I_{SD} < 1µA, ThinSOT Package
LT1962	300mA, Low Noise Micropower, LDO	V_{IN} : 1.8V to 20V, $V_{\text{OUT}(\text{MIN})}$ = 1.22V, V_{D0} = 0.27V, I_{Q} = 30µA, I_{SD} <1µA, MS8 Package
LT1964	200mA, Low Noise Micropower, Negative LDO	V_{IN} : -0.9V to -20V, $V_{OUT(MIN)}$ = -1.21V, V_{DO} = 0.34V, I_Q = 30µA, I_{SD} 3µA, ThinSOT Package
LT1965	1.1A, Low Noise, Low Dropout Linear Regulator	290mV Dropout Voltage, Low Noise: $40\mu V_{RMS}$, V_{IN} : 1.8V to 20V, V_{OUT} : 1.2V to 19.5V, stable with ceramic caps, TO-220, DD-Pak, MSOP and 3mm × 3mm DFN Packages
LT3020	100mA, Low Voltage V _{LDO,} V _{IN(MIN)} = 0.9V	V _{IN} : 0.9V to 10V, V _{OUT(MIN)} = 0.20, V _{D0} = 0.15V, I _Q = 120µA, I _{SD} <3µA, DFN, MS8 Packages
LT3023	Dual, 2x 100mA, Low Noise Micropower, LDO	V_{IN} : 1.8V to 20V, $V_{OUT(MIN)}$ = 1.22V, V_{DO} = 0.30V, I_Q = 40µA, I_{SD} <1µA, DFN, MS10 Packages
LT3024	Dual, 100mA/500mA, Low Noise Micropower, LDO	V_{IN} : 1.8V to 20V, $V_{OUT(MIN)}$ = 1.22V, V_{DO} = 0.30V, I_Q = 60µA, I_{SD} <1µA, DFN, TSSOP Packages
LT3080/ LT3080-1	1.1A, Parallelable, Low Noise, Low Dropout Linear Regulator	300mV Dropout Voltage (2-Supply Operation), Low Noise: $40\mu V_{RMS}$, V_{IN} : 1.2V to 36V, V_{OUT} : 0V to 35.7V, current-based reference with 1-resistor V_{OUT} set; directly parallelable (no op amp required), stable with ceramic caps, TO-220, SOT-223, MSOP and 3mm × 3mm DFN Packages; "-1" version has integrated internal ballast resistor

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